Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.120 inches	s and 0.200 inches
Terminal Length:	
Between 1.000 inches	s and 1.500 inches
Overall Diameter:	
Between 0.055 inches	s and 0.090 inches
Joint Electronic Dev	ice Engineering Council/jedec/case Outline Designation:
Do-35	
Mounting Method:	
Terminal	
Features Provided:	
Quality assurance lev	el txv
Semiconductor Mate	erial:
Silicon	
Voltage Rating In Vo	olts Per Characteristic:
36.0 regulator voltag	je
Voltage Tolerance Ir	n Percent:
-5.0/+5.0	
Current Rating Per C	Characteristic:
3.40 milliamperes all	primaries horsepower metric
Power Rating Per Cl	naracteristic:
400.0 milliwatts small	-signal input power, common-collector preset
Maximum Operating	Tempurature Per Measurement Point:
200.0 degrees celsius	s ambient air
Test Data Document	
81349-mil-s-19500 sp	pecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes corr	nmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and pe	rformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And (	Quantity:
2 uninsulated wire lea	ud and a second s
Specification Data:	
81349-mil-s-19500/11	7 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	